

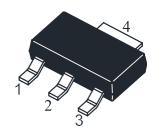


# **NPN Silicon Epitaxial Planar Transistors**

#### **Features**

- AEC-Q101 Qualified
- Halogen and Antimony Free(HAF), RoHS compliant

# Pb RoHS COMPLIANT



### **Mechanical Data**

• SOT-223 Plastic Package

• Mounting position: Any

1.Base 2.Collector 3.Emitter 4. Collector SOT-223 Plastic Package

Absolute Maximum Ratings (TA=25°C unless otherwise noted)					
Parameter	Symbol	Value	Unit		
Collector Base Voltage	V <sub>СВО</sub>	100	٧		
Collector Emitter Voltage	VCEO	80	V		
Emitter Base Voltage	V <sub>EBO</sub>	5	٧		
Collector Current	lc	1	Α		
Peak Collector Current	Ісм	1.5	Α		
Peak Base Current	Івм	0.2	Α		
Total Power Dissipation	P <sub>tot</sub>	1.33	W		
Junction Temperature	Tj	150	°C		
Storage Temperature Range	$T_{stg}$	- 65 to + 150	°C		

Thermal Characteristics					
Parameter	Symbol	Value	Unit		
Thermal Resistance Junction to Ambient <sup>1)</sup>	R <sub>thJA</sub>	94	°C/W		

 $<sup>^{1)}</sup>$  Device mounted on FR-4 substrate PC board, 2oz copper, with 1-inch square copper plate in still air.





Electrical Characteristics (T <sub>A</sub> =25°C unless otherwise noted)						
Parameter		Symbol	Min.	Тур.	Max.	Unit
DC Current Gain at $V_{CE} = 2 \text{ V}$ , $I_C = 5 \text{ mA}$ at $V_{CE} = 2 \text{ V}$ , $I_C = 500 \text{ mA}$ at $V_{CE} = 2 \text{ V}$ , $I_C = 150 \text{ mA}$	ABCP56-10Q ABCP56-16Q	h <sub>FE</sub>	25 25 63 100	-	- - 160 250	-
Collector Base Cutoff Current at V <sub>CB</sub> = 30 V		Ісво	-	-	100	nA
Emitter Base Cutoff Current at V <sub>EB</sub> = 5 V		I <sub>EBO</sub>	-	-	100	nA
Collector Base Breakdown Voltage at I <sub>C</sub> = 100 µA		V <sub>(BR)</sub> CBO	100	-	-	V
Collector Emitter Breakdown Voltage at I <sub>C</sub> = 1 mA		V <sub>(BR)CEO</sub>	80	-	-	V
Emitter Base Breakdown Voltage at $I_E = 100 \mu A$		V <sub>(BR)EBO</sub>	5	-	-	V
Collector Emitter Saturation Voltage at $I_C = 0.5 \text{ A}$ , $I_B = 50 \text{ mA}$		V <sub>CE(sat)</sub>	ı	-	500	mV
Base Emitter Saturation Voltage at $I_C = 0.5 \text{ A}$ , $I_B = 50 \text{ mA}$		V <sub>BE(sat)</sub>	-	-	1.1	V
Base Emitter Voltage at V <sub>CE</sub> = 2 V, I <sub>C</sub> = 0.5 A		V <sub>BE</sub>	-	-	1	V
Transition Frequency at $V_{CE} = 5 \text{ V}$ , $I_{C} = 10 \text{ mA}$ , $f = 100 \text{ MHz}$		f⊤	-	130	-	MHz





#### **Typical Characteristics Curves**

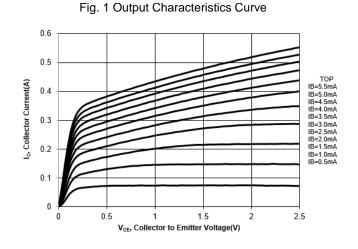


Fig. 2 Collector Current vs. Base to Emitter Voltage

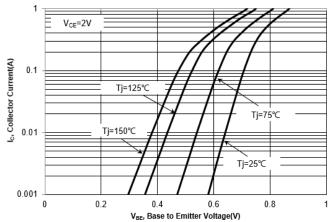


Fig. 3 DC Current Gain vs. Collector Current

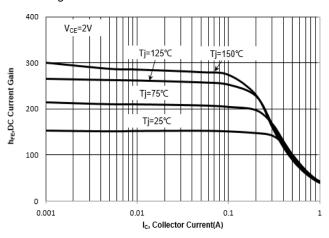


Fig. 4 V<sub>BE(sat)</sub> vs. Collector Current

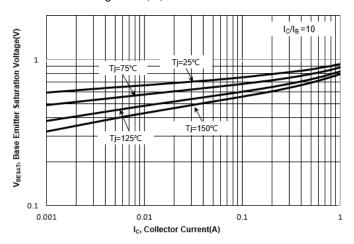


Fig. 5 V<sub>CE(sat)</sub> vs. Collector Current

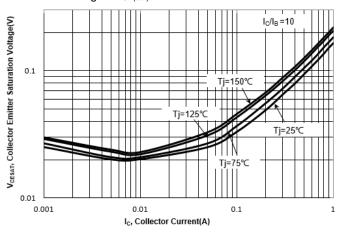


Fig. 6 Output Capacitance

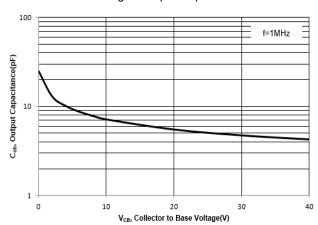
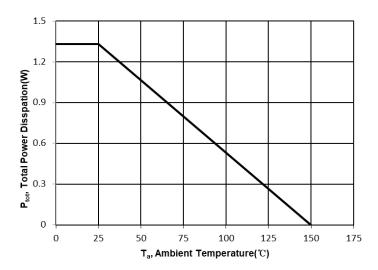






Fig. 7 Power Derating Curve

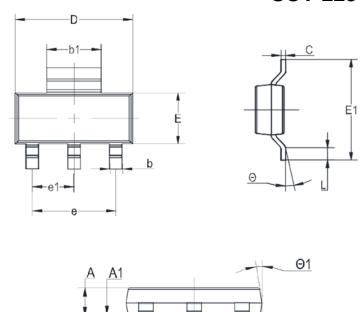






# Package Outline Dimensions (Unit: millimeters)

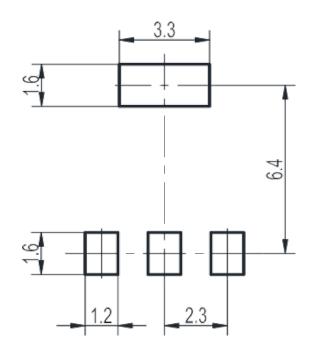
## **SOT-223**



SYMBOL	MILLIMETER				
	MIN	TYP	MAX		
А	1.5	/	1.8		
A1	/	/	0.1		
b	0.6	/	0.8		
b1	2.9	/	3.1		
С	0.22	/	0.32		
D	6.3	/	6.7		
E	3.3	/	3.7		
E1	6.7	/	7.3		
е	/ /		4.6		
e1	/	/	2.3		
L	L 0.7 /		1.1		
Θ	0°	/	10°		
Θ1	0°	/	7°		
Θ2	0°	/	7°		

# **Recommended Soldering Footprint** (Unit: millimeters)

Θ2





# **GOOD-ARK Electronics**

### **Packing Information**

Package	Tape Width	Pitch		Reel Size		Per Reel Packing
SOT 222	mm	mm	inch	mm	inch	Quantity
SOT-223	12	8±0.1	0.315±0.004	330	13	3000

### **Marking information**

" BCP56-\*\*Q " = Part No. (" \* " = HFE grouping Code)

" \*\*\*\* " = Date Code Marking

Font type: Arial



### **Revision History**

Version	Date	Major Changes
Rev.A	2025.01.19	Official Release



#### GOOD-ARK Electronics

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